

SBRF2060CT - SBRF20200CT

Isolation 20.0 AMPS. Schottky Barrier Rectifiers **ITO-220AB**



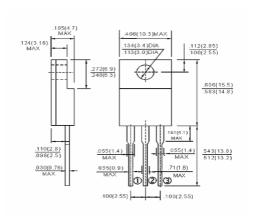


Features

- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Guardring for overvoltage protection
- High temperature soldering guaranteed: 260°C/10 seconds,0.25"(6.35mm)from case

Mechanical Data

- Cases: ITO-220AB molded plastic
- Terminals: Leads solderable per MIL-STD-750, Method 2026 Polarity: As marked **♦**
- Mounting position: Any
- Mounting torque: 5 in. lbs. max Weight: 0.08 ounce, 2.24 grams





Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	SBRF 2060CT	SBRF 20100CT	SBRF 20150CT	SBRF 20200CT	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	60	100	150	200	V
Maximum RMS Voltage	V_{RMS}	42	70	105	140	V
Maximum DC Blocking Voltage	V_{DC}	60	100	150	200	V
Maximum Average Forward Rectified Current at T _c =135°C Total device Per Leg	I _(AV)	20 10				Α
Peak Repetitive Forward Current Per leg (Rated V _R , Square Wave, 20KHz) at Tc=135°C	I _{FRM}	20				А
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	150				Α
Peak Repetitive Reverse Surge Current (Note 1)	I_{RRM}	0.5				Α
$\begin{array}{ll} \text{Maximum Instantaneous Forward Voltage at} \\ \text{(Note 2)} & I_F = 10\text{A, } \text{Tc} = 25^{\circ}\text{C} \\ & I_F = 10\text{A, } \text{Tc} = 125^{\circ}\text{C} \\ & I_F = 20\text{A, } \text{Tc} = 25^{\circ}\text{C} \\ & I_F = 20\text{A, } \text{Tc} = 125^{\circ}\text{C} \\ \end{array}$	V_{F}	0.80 0.70 0.95 0.85	0.85 0.75 0.95 0.85	0.95 0.85 1.05 0.95	0.99 0.87 1.23 1.10	V
Maximum Instantaneous Reverse Current @ Tc=25 °C at Rated DC Blocking Voltage @ Tc=125 °C	I_R	10	0.1 0.15 10 5 100			mA
Voltage Rate of Change, (Rated V _R)	dV/dt	10	10,000			V/uS
Typical Thermal Resistance Per Leg (Note 3)	R _{θJC}	3.5			°C /W	
Typical Junction Capacitance	Cj	310				pF
RMS Isolation Voltage (MBRF Type Only) from Terminals to Heatsink with t=1.0 Second, RH $\leq 30\%$	V _{ISO}	4500 (Note 4) 3500 (Note 5) 1500 (Note 6)				V
Operating Junction Temperature Range	T_J	-65 to +150				°C
Storage Temperature Range	Tstg	-65 to +175				°C

Notes: 1. 2.0us Pulse Width, f=1.0 KHz

- 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle
- 3. Thermal Resistance from Junction to Case Per Leg, with Heatsink Size (4"x6"x0.25") Al-Plate
- 4. Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset.
- 5. Clip Mounting (on case), where leads do overlap heatsink.
- 6. Screw Mounting with 4-40 screw, where washer diameter is \leq 4.9 mm (0.19")



RATINGS AND CHARACTERISTIC CURVES (SBRF2060CT THRU SBRF20200CT)



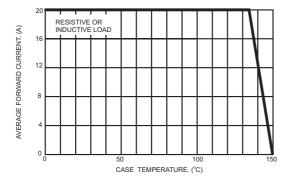


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG

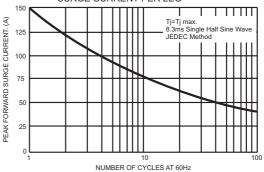


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER LEG

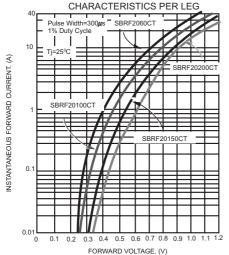


FIG.4- TYPICAL REVERSE CHARACTERISTICS

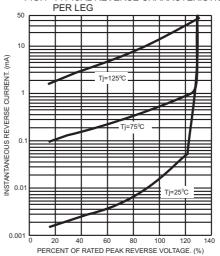


FIG.5- TYPICAL JUNCTION CAPACITANCE PER LEG

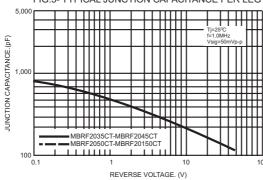


FIG.6- TYPICAL TRANSIENT THERMAL IMPEDANCE

